

## **INCHANGE SEMICONDUCTOR**

# isc N-Channel MOSFET Transistor

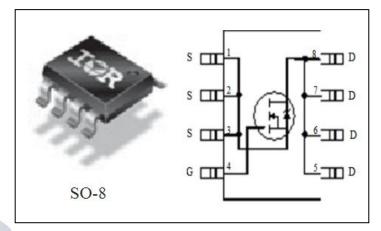
## **IRF7473TRPBF**

### • FEATURES

- With SOP-8 packaging
- High speed switching
- Easy to use
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

## APPLICATIONS

- Power supply
- DC-DC converters
- Motor control
- Switching applications



### • ABSOLUTE MAXIMUM RATINGS(T<sub>a</sub>=25℃)

SYMBOL	PARAMETER		VALUE	UNIT	
V <sub>DSS</sub>	Drain-Source Voltage		100	V	
V <sub>GSS</sub>	Gate-Source Voltage		±20	V	
ID	Drain Current-Continuous	Tc=25℃ Tc=75℃	6.9 5.5	A	
I <sub>DM</sub>	Drain Current-Single Pulsed		55	А	
P <sub>D</sub>	Power Dissipation		2.5	W	
Tj	Operating Junction Temperature		-55~150	°C	
T <sub>stg</sub>	Storage Temperature		-55~150	°C	

### • THERMAL CHARACTERISTICS

SYMBOL	PARAMETER		UNIT	
Rth(ch-a)	Channel-to-ambient thermal resistance		°C/W	

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### **ELECTRICAL CHARACTERISTICS**

#### $T_{C}\text{=}25^{\circ}\!\!\!\!\mathrm{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	МАХ	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; I <sub>D</sub> = 0.25mA	100			v
V <sub>GS</sub> (th)	Gate Threshold Voltage	V <sub>DS</sub> =±20V; I <sub>D</sub> =0.25mA	3.5		5.5	v
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> = 10V; I <sub>D</sub> =4.1A		22	26	mΩ
I <sub>GSS</sub>	Gate-Source Leakage Current	V <sub>GS</sub> = ±20V;V <sub>DS</sub> = 0V			±0.1	μA
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> = 95V; V <sub>GS</sub> = 0V;Tj=25℃ V <sub>DS</sub> = 80V; V <sub>GS</sub> = 0V;Tj=150℃			1 250	μA
V <sub>SDF</sub>	Diode forward voltage	I <sub>SD</sub> =4.1A, V <sub>GS</sub> = 0 V			1.3	V

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